

KBJL4JV thru KBJL4MV

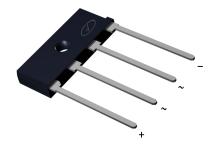
Glass Passivated Bridge Rectifiers Reverse Voltage 600 to 1000V Forward Current 4A

Features

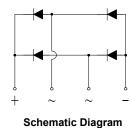
- Thin single In-line package
- Ideal for printed circuit boards
- Glass passivated chip junction
- Low profile package
- High surge current capability
- High case dielectric strength of 2000 V_{RMS}
- Plastic package has Underwrites Laboratory



- Case: KBJL
- Epoxy meets UL-94V-0 Flammability rating
- Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102, E3 suffix for customer grade, meet JESD 201
- High temperature soldering guaranteed:Solder Dip 275°C, 40seconds
- Polarity: As marked on body
- Mounting Torgue: 5.7cm-kg (5.0inches-lbs) max
- Recommend Torgue: 5.7cm-kg (5inches-lbs)



Package: KBJL





Maximum Ratings and Electrical Characteristics

(T_A=25°C unless otherwise noted)

Parameter	Symbol	KBJL4JV	KBJL4KV	KBJL4MV	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	600	800	1000	V
Maximum Average Forward Rectified T_C =110°C Output Current at T_A =25°C	I _{F(AV)}	4.0 ⁽¹⁾ 2.6 ⁽²⁾			А
Peak Forward Surge Current (8.3 ms single sine-wave superimposed on rated load, JEDEC method)	I _{FSM}	150			А
Rating for Fusing (t<8.3ms)	l ² t	93			A ² sec
Maximum Instantaneous Forward Voltage Drop per Leg at 2A	V _F	0.96			V
Maximum DC Reverse Current at Rated T_A =25°C DC Blocking Voltage per Leg T_A =125°C	I _R	5 150			μΑ
Typical Thermal Resistance per Leg	R _{eJA} R _{eJC}	26 ⁽²⁾ 2.5 ⁽¹⁾			°C/W
Operating Junction and Storage Temperature Range	T_J , T_{STG}	-55 to +150			°C

Notes:

- 1). Unit case mounted on Al plate heatsink
- 2). Units mounted on PCB without heatsink



KBJL4JV thru KBJL4MV

Glass Passivated Bridge Rectifiers Reverse Voltage 600 to 1000V Forward Current 4A

Typical Characteristic Curves

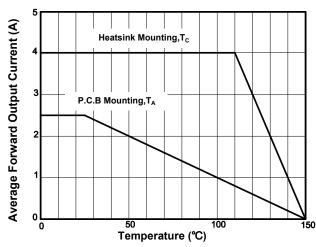


Figure 1. Derating Curve Output Rectified Current

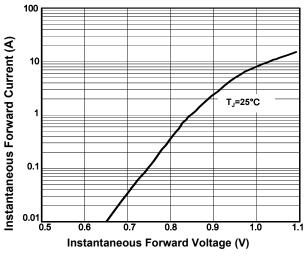
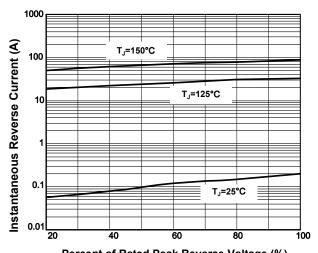


Figure 3. Typical Forward Characteristics Per Diode



Percent of Rated Peak Reverse Voltage (%)
Figure 5. Typical Reverse Characteristics Per Diode

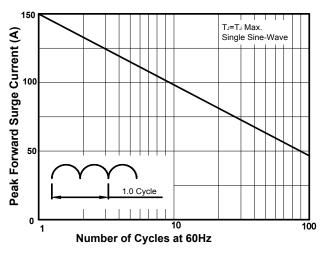


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current per Diode

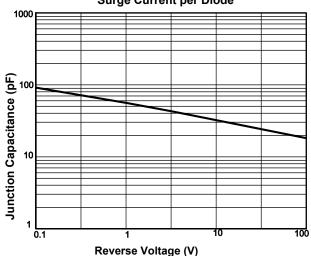


Figure 4. Typical Junction Capacitance Per Diode



KBJL4JV thru KBJL4MV

Glass Passivated Bridge Rectifiers
Reverse Voltage 600 to 1000V Forward Current 4A

Product Outline Dimensions

in mm KBJL

